M echanism s for electron transport in atom ic-scale one-dim ensional w ires: soliton and polaron e ects

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We study one-electron tunneling through atom ic-scale one-dimensional wires in the presence of coherent electron-phonon (e-ph) coupling. We use a full quantum model for the e-ph interaction within the wire with open boundary conditions. We illustrate the mechanism s of transport in the context of molecular wires subject to boundary conditions imposing the presence of a soliton defect in the molecule. Competition between polarons and solitons in the coherent transport is exam ined. The transport mechanism s proposed are generally applicable to other one-dimensional nanoscale system s with strong e-ph coupling.

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I. IN TRODUCTION

How will an electronic system conduct in the limit where it becomes entirely one-dimensional? This became an issue in the late 1980s, with the fabrication of sem iconductor structures that possessed only a single conducting \channel", and which exhibited the phenom enon of quantized conductance [1]. With nanoscale fabrication techniques, the class of e ectively one-dimensional system shas expanded to include: atom ic-scale structures on surfaces produced by scanning probe lithography [2], self-assembly [3], or directed assembly [4]; break junctions [5,6]; carbon nanotubes [7]; and conjugated organic m olecules [8]. The m easurem ent of the transport properties of individual examples of such system s is now possible; for example, conduction in individual molecules has recently been m easured by scanning probes [9,10] or bulk electrodes [8,11]; transport in nanotubes has been m easured using lithographed electrodes [12]. Sim ilar measurements may also soon become possible for atom icscale wires on surfaces.

M any of these recent examples approach the ideal of a system whose atom ic | as well as electronic | structure is truly one-dimensional. As such they may be expected to exhibit enhanced e ects of correlations during electron transport. Electron-electron correlations have consequences including the possible form ation of Luttinger liquids [13]; on the other hand, the elects produced by electron-atom correlations can include the Peierls transition [14], which opens a gap at the Femi ienergy and renders one-dimensionalmetallic systems sem iconducting. If these quasi-one-dimensional systems are to have applications in nanotechnology, it is vital to understand whether currents can pass through them, despite the possibility of a Peierls transition. In this paper we address this question, in the context of molecular wires; speci cally, we consider nite-length poly-acetylene chains described by a fully quantum version of the Su{Schrie er{Heeger (SSH) model [15].

We have chosen to study molecular conductors here, rather than any of the other types, because electronlattice coupling in bulk samples is relatively well studied [15]. The Peierls transition manifests itself in an alternation of single and double bonds (i.e., dimerisation) along the molecule's length, and bulk electron transport is dominated by mobile intrinsic defects formed when electrons or holes are injected into this dimerised structure. For our purposes them ost in portant defects are polarons (which can be thought of as a local reduction in the dimerisation around an injected charge) and charged solitons (topological defects in the bond length alternation). The soliton has an associated electronic state at mid-gap and the dimerisation changes sign, passing through zero in the neighbourhood of the defect [15].

In order to understand m olecular charge transport on nanom etre lengthscales, we must develop a theory of coherent transport that accounts for polaron and soliton form ation. We took the rst steps recently when we showed that the tunneling of carriers through m olecular wires at low temperature is dram atically enhanced by the form ation of virtual polarons [16]. Therefore, previous treatments of tunneling in m olecules based on elastic scattering signi cantly underestim ate the conductance [17]. However, the boundary conditions used in our previous work prevented solitons from forming in the m olecule, as the dimerisation was constrained to be equal at both ends. In the present paper we study chains with an odd num ber ofm onom ers; the ground state of such a

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system possesses a single soliton in the centre [15,18]. We are thus able to study for the rst time the role of the moving soliton, with its associated m id-gap state, and the competition between polarons and solitons in coherent transport.

II.PHYSICAL MODEL

The model for the molecular wires includes delocalized -electrons interacting with quantum phonons. The electronic H am iltonian is expressed in the basis of the one-electron eigenstates (labelled by n;m) of the reference system. The e-ph coupling is linear in the phonon displacements and induces transitions between electronic states. The molecule H am iltonian is

$$H = X X X X X n c_{n}^{y} c_{n} + h! a^{y} a + n_{m} (a^{y} + a) c_{n}^{y} c_{m}$$

(1)

where c_n^y (c_n) creates (annihilates) an electron in the nth electronic state with energy $_n$ and a^y (a) creates (annihilates) a quantum of energy h! in the eigenmode of vibration of the isolated molecule. The values of $_n$, ! and $_{nm}$ are calculated from the ground state of the neutral molecule (described by the SSH model [15,16]) containing an odd number N of monomers. The vibrational eigenmodes V and frequencies of the molecule are calculated within the harm onic approximation [19].

To calculate the transport properties through the wire, the left and right ends of the molecule (atom ic sites i = 1 and i = N) are connected to metallic leads via hopping integrals $v_{L,R}$ respectively. The leads are modeled as one-dimensional sem i-in nite tight-binding chains with on-site energy $_{L,R}$ and inter-site hopping matrix elements $_{L,R}$ (with no e-ph coupling). The scattering states j i for a single incoming charge carrier are expanded inside the molecule onto the eigenstates j; fn gi = c_n^{Y} (a^{Y})ⁿ = $\frac{P}{n}$] ji, of the non-interacting e-ph system ¹. n is the occupation number of the phonon mode and ji is the vacuum state (representing the neutral ground state of the whole system,

with a de nite number of electrons in each part). The single added carrier can be anywhere in the system (on the left, the right, or in the molecule) and interacts with phonons only when inside the molecule. We only consider current-carrying states in which a single electron is added to the ground state; we expect this assumption to hold since the interval between electron transm ission is much greater than the transit time [16].

We now brie y outline the calculation technique. The transport problem is solved by mapping the many body (one-electron/m any-bosons) problem onto a singleelectron problem with many scattering channels [20,16]. Each channel represents the di erent scattering processes by which the electron might exchange energy with the phonons. For an initial phonon distribution b fm q and an incoming electron from the left lead, the outgoing channels in the left and right leads are associated ; with energy-dependent rejection r_{ab} () and transmission t_{ab} () coe cients respectively (a fn g is the phonon distribution after scattering in each outgoing channel). In the leads, the scattering states take the asym potic form of propagating B loch waves with am plitudes rab (re ection) and $t_{ab}\,$ (transm ission). The wave vectors are given by the dispersion relations in each channel. For example, the energy in of the incoming electron from the left lead is related to the wave vector k_b^L by the tight-bindinglike dispersion relation $_{\rm in}$ = $_{\rm L}$ + 2 $_{\rm L}\cos k_{\rm b}^{\rm L}$. For the nalenergy fin of the electron transmitted to the right, one has: $fin = R + 2 R cosk_a^R$. One can then project out the leads from the problem and work in the molecular wire subspace to solve for the value of the scattering state j (E)i. This state is obtained from propagating the source term is (E) i (incoming electron from the left) via the e ective G reen's function G (E) de ned in the molecular wire subspace: j (E) i = G (E) js (E) i, where G is given by G(E) = E H _L (E) _R (E)]¹, H is the molecular wire H am iltonian de ned in Eq. (1) and $_{L,R}$ (E) are complex potentials arising from embedding the molecular wire spectrum into the continuum of states associated with the leads. O verall energy pis conserved, m h! = so in and fin are related by: E = in + inn h! ². fin +

The linear system ji = G jsi is solved for a nite size

¹ A sim ilar expansion is used in the leads, c_n^{n} is then replaced by the charge creation operator d_i^{y} on site i.

² In this paper, we consider the lim it of low temperatures: the initial phonon distribution is b fm g = f0g where all optic phonon modes are in the ground state (in this lim it, the injection energy equals the total energy $_{in} = E = _{fin} + _{n} h!$). It is a very good approximation even at room temperature for alloptic modes except the soliton translation. For the soliton translation the condition kT h! restricts us to T 230K.

basis set by truncating the phonon subspace (i.e considering the lowest occupation numbers up to $n_{occ}^{m\ ax}$ in each mode). Furthermore the electron is coupled inside the molecule to a nite number N $_{ph}$ of the most relevant phonon modes (see next section). A detailed analysis of the validity of such approximations can be found in Ref. [16]. From the solution j i = G jsi, one can obtain the relection r_{ab} and transmission t_{ab} coe cients for all the channels and hence the currents owing through the wire. One can also calculate the expection values of any correlation functions between the electron and phonon degrees of freedom.

We dene the transmission probability $T_{ab} = f_{ab}(_{in})f_{R} \sin k_{a}^{R}(_{fin}) = (_{L} \sin k_{b}^{L}(_{in}))^{3}$. In our model, $f_{ab}f_{a}$ is proportional to $f_{il} = N$; $a_{j}i_{j}j_{l}^{2} = f_{j}N$; $a_{j}G_{j}j_{i}f_{j}^{2}$ and the source term is proportional to the velocity of the incom ing electron [16]. Then, working in the real-space representation, the inelastic transmission probability can be rewritten in the following usual form [21]:

$$T_{ab}(f_{in}; i_{n}) = 4 \frac{v_{L}^{2}}{L} \sin k_{b}^{L}(f_{in}) \frac{v_{R}^{2}}{R} \sin k_{a}^{R}(f_{in})$$
$$\dot{m} = N \ \dot{J}G_{ab}(E) \ \dot{J} = 1 \dot{I} \dot{J}; \quad (2)$$

where $hN \not G_{ab}(E) \not Ii$ is the matrix element of the G reen's function G taken between the left side i = 1 and the right side i = N of the molecule and the phonon con gurations before (b) and after (a) scattering ⁴.

III. R E SU LT S

First we describe the vibrationalm odes needed to obtain the relevant distortions of the molecule. We have shown that polaron formation inside the molecule after charge injection is due to the coupling to the longwavelength optic modes [16]. For odd-number chains where a soliton defect is present, we have to include in addition the modes responsible for the motion and the deformation of the soliton. We therefore include the soliton translation (the Goldstone mode'), the amplitude mode' related to the deformation of the soliton width, and higher-order deformation modes (for example the socalled third mode) [15,22]. Figure 1 shows the phonons considered for a molecule of length N = 99. As an illustrative example, we also show in Fig. 2 the dimerisation d_j for neutral isolated even- and odd-length molecules. The dimerisation is obtained, in term sofatom is displacements u_j, from the staggered di erence between adjacent bond lengths: d_j = (1)^j (u_{j+1} 2u_j+u_{j1}). For even N, the neutralmolecule is perfectly dimerized: the dimerisation d_c is constant in the middle of the chain despite the end e ects. For odd N, a soliton appears in the middle of the two domains of opposite sign of dimerisation.

Now we turn on the lattice deform ations induced by electron propagation in the (odd N) m olecule connected to the electrodes ⁵. The lattice deform ations induced by the tunneling electron are given by the correlation function ^[i] between the electron density $P_j = \frac{c_j^v c_i}{h=2M}$ of the and the displacement = $(a + a^y)^{p} \frac{h=2M}{h=2M}$ of the mode as ^[i] = $hP_j^v P_j i=hP_i i$. We also de ne the distortion on site j due to the displaced modes when the electron is on site i as $u_j^{[i]} = P_j^{p} (j)$. The dimensional tion pattern $d_j^{[i]}$ is then calculated from $u_j^{[i]}$.

We plot on Fig. 3 the absolute value of the dimerisation $d_i^{[i]}$ from which the constant dimerisation d_c and the end e ects have been subtracted (the corresponding pattem for the isolated molecule is shown on Fig. 2). Such a choice perm its us to represent the defects with more contrast. For an injection energy E = 0 at m id-gap, the corresponding dimerisation is shown on Fig. 3(a). The bright feature around the middle of the chain represents the soliton. In the absence of e-ph coupling, this would correspond to charge in jection in resonance with the oneelectron soliton level (see the transm ission curve below). The soliton would then be immobile, its position xed in the middle of the chain and its width unchanged (i.e. straight vertical feature around j = 50). However due to the e-ph coupling, the soliton defect becom es m obile and its width varies while the electron progates. Sim ilar behaviour is observed for other in jection energies around mid-gap. As E approaches the valence band edge the mechanisms become dierent, as shown on Fig. 3(b). In parallel with the soliton delocalization and deform ation, one observes the form ation of a polaron. This is characterized by the extra bright feature around the st

 $^{^3}$ $T_{\rm ab}$ contains as usual the ratio of the velocity in the outgoing channel to that in the incom ing channel.

⁴ The factors $v_{L,R}^2 = L_{R} \sin k_{b,a}^{L,R}$ in Eq.(2) are related to the im aginary parts of the potentials L_{R} .

 $^{^5}$ Calculations were performed for an electron coupled to the N _{ph} = 5 lowest frequencies modes shown in Fig. 1 and n_{occ}^{max} = 4. Calculations were also done for other sets of parameters. The same qualitative physics remain when the results are converged versus the basis set size.

diagonal in Fig. 3(b). In principle, the (virtual) polaron corresponds to a local reduction of the dimerisation around the (tunneling) electron [16]. However it appears as an increase (positive number) since $jl_j^{[1]}j$ is plotted on Fig. 3(b). Furtherm ore, the corresponding dimerisation is not simply the superposition of the polaron and the soliton | the two defects interact strongly together. For example, the dimerisation pattern for an electron at position i 25 is characteristic of a merging of both the polaron and soliton. Such mechanism s, leading to strong lattice distortions, would be expected to a ect the transm ission through them olecularwires | e ects that we now consider.

We de ne an e ective total transmission probability T (E) arising from the contribution of the di erent outgoing channels as T (E) $_{a} T_{ab} (_{fin}; _{in}) (_{fin} +$ in) (see Fig. 4). W ithout e-ph coupling, n h! the transm ission curve presents the usual features: resonances at energies corresponding to the one-electron levels of the molecule with alm ost perfect transmission, and strong suppression of the transmission in the band-gap of the molecule for which propagation occurs by tunneling. The soliton resonance (at mid-gap) is much narrower than the other resonances. This is to be expected since the corresponding one-electron (soliton) state is much more localized than the other states. W ith e-ph interaction, we have already shown that a polaron can be form ed in the molecule and that the soliton position and width are strongly modi ed. Such mechanisms a ect the transm ission in the following way: (i) the delocalization and deform ation of the soliton broaden but low er the resonance peak at m id-gap, (ii) for larger in jection energies, the form ation of the polaron e ectively reduces the apparent band-gap, and a polaron resonance peak appears 0.42 eV for the N = 99 w ire) inside the original (at E gap. This e ective band-gap reduction correlatively increases the transmission in the tunneling regime (i.e. for injection energies in the gap).

$\ensuremath{\texttt{IV}}$. C O N C LU S IO N

The results presented above demonstrate the complexity of electronic transport through one-dimensional atom ic-scale wires. We have illustrated the mechanisms of electron transport in molecular wires when e-ph interactions are included. Owing to e-ph coupling, polarons can be formed inside the molecule. Polaron propagation is the main mechanism of transport through perfectly dimerised (sem iconducting) molecules. The presence of a mid-gap state associated to a soliton defect in the middle of the molecule involves di erent mechanisms for the transport. For injection energies around the mid-gap state, the delocalisation and deformation of the soliton is the main mechanism for electron transfer. W ith larger

injection energies (still inside the energy band-gap of the molecule), a virtual polaron can be form ed. The transport is then associated with more complicated mechanisms involving the interaction of both polaron and soliton. However in most cases, the elective reduction of the band-gap due to polaron form ation, the delocalization and deformation of the soliton and the polaron-soliton interaction increase the transmission in the tunneling regime. Although we studied a model derived from organic molecules, there is good reason to believe that the e-ph coupling in other one-dimensional nanoscale wires is likely to give rise to sim ilar phenom ena. In the case of carriers injected into dangling-bond lines on the Si(001) surface [2], polaron states which are in many respects analogous to those in molecular wires are also formed [23]. Speci cally, we expect the present results to be valid for any atom ic-scale wire in which there is a degeneracy between two di erent values of som e order param eter (the dimerisation in the molecular case, the surface dim er buckling in the dangling bond line) which are related by a discrete sym m etry and strongly coupled to the electrons.

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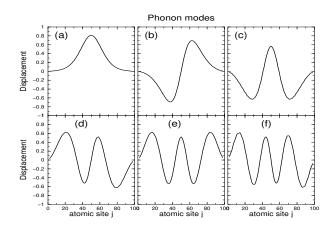


FIG.1. Optic component of the phonon modes for a chain length N = 99. The optic component is de ned as: ($1)^{j}$ (V (j + 1) 2V (j) + V (j 1)). (a) is the mode associated with the soliton translation (h!_a=0.020 eV), (b) with the deformation of the soliton width (h!_b=0.114 eV), (c) is the so-called third mode (h!_c=0.134 eV). (d,e,f) are other long-wavelength opticm odes (h!_d:e;f=0.144, 0.152, 0.158 eV).

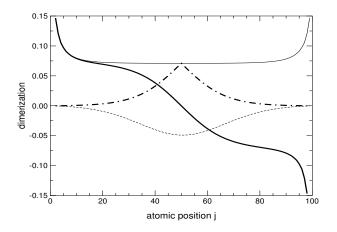


FIG.2. Dimerisation d_j (in A) for isolated neutral molecules. This solid line: N = 100, for even N, d_j is constant (d_c) in the middle of the chain. Solid line: N = 99, for odd N, a soliton exists in the middle of the chain separating two domains of dimerisation with opposite site. Dot-dashed line: the absolute value $jd_j j$ from which d_c and the end e ects are substracted (N = 99). This dashed line: deformation induced by adding an extra electron in the chain N = 100; the local reduction of the dimerisation represents a polaron.

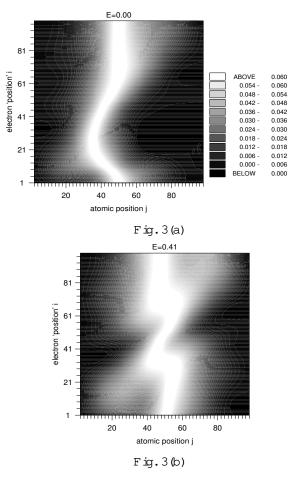


FIG.3. Two-dimensional (atom ic j/electron i positions) map of the dimension $d_j^{[i]}$ (in A) obtained from the atom ic distortions $u_j^{[i]}$ for the N = 99 wire length. Here we plot the absolute value $jd_j^{[i]}$ j substracting d_c and the end e ects. The incoming electron propagates from the left to the right. (a) Injection at mid-gap (E = 0.0): the bright feature represents the soliton whose position and width vary for the diment electron positions i taken to calculate $d_j^{[i]}$. (b) Injection at E = 0.41 eV close the polaron resonance peak in the transmission (Fig. 4): a virtual polaron is form ed (bright feature across the rst diagonal). The maximum change in $jd_j^{[i]}$ j is 0.03 0.04A around the polaron and 0.07A around the soliton.

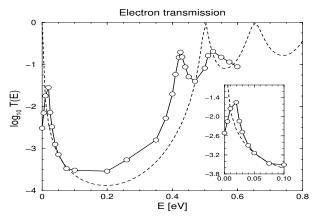


FIG.4. Transmission probability T (E) versus the energy E for a molecular wire of length N = 99. D ashed line: transmission through a rigid chain containing a soliton defect (see the sharp peak at E = 0 corresponding to the soliton state resonance). Solid line with circles: transmission when the e-ph coupling is included. The delocalisation of the soliton and the polaron-soliton interaction broaden the resonance peak at m id-gap into a \miniband" (shown in the inset, enlarged low-energy region). The polaron resonance peak appears around E 0:42 eV.